

**GENERAL DESCRIPTION**

The 46104 is a stable common emitter transistor capable of providing 4 watts of CW RF output power across the 500-1000 MHz frequency band. This transistor is specifically designed for Class A, AB and C general purpose amplifier applications. It utilizes gold metallization and diffused ballasting to provide high reliability and supreme ruggedness.

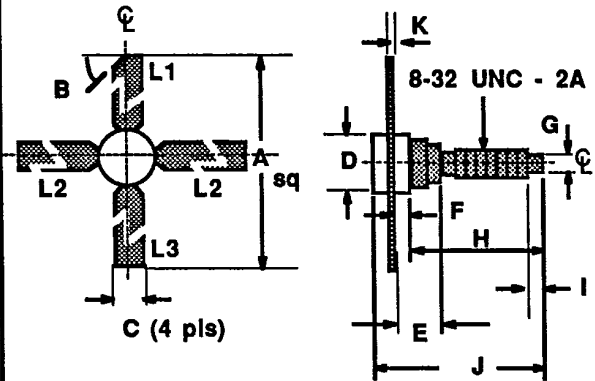
**46104**  
**4 WATTS - 28 VOLTS**  
**1000 MHZ**

**UHF COMMUNICATIONS**

**ABSOLUTE MAXIMUM RATINGS**

|   |       |
|---|-------|
| Maximum Power Dissipation @ 25°C Case Temperature | 10 W  |
| Maximum Voltage and Current                       |       |
| BVces Collector to Emitter Voltage                | 50 V  |
| BVebo Emitter to Base Voltage                     | 4.0 V |
| Ic Collector Current                              | 0.5 A |

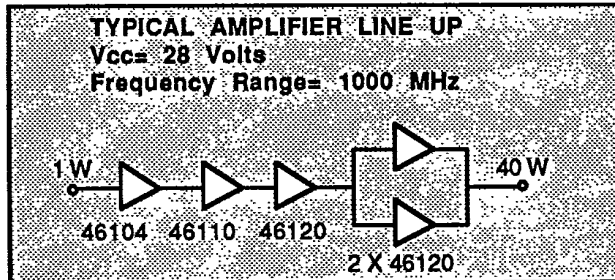
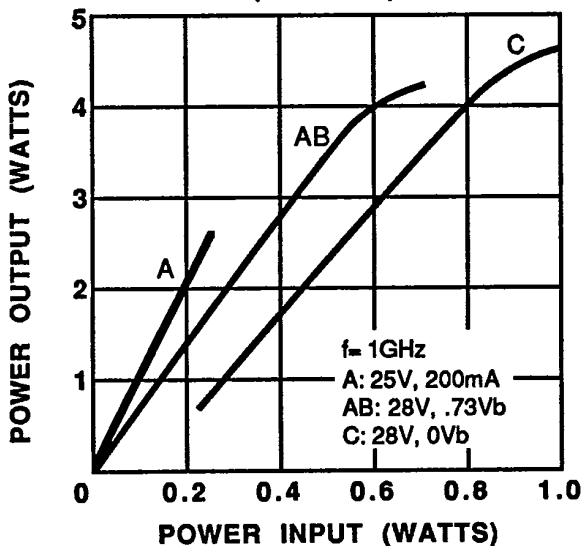
|                                |               |
|--------------------------------|---------------|
| Maximum Temperatures           |               |
| Storage Temperature            | -65 to +150°C |
| Operating Junction Temperature | +200°C        |



L1 : C  
 L2 : E  
 L3 : B

| DIM | Millimeter | TOL | Inches   | TOL  |
|-----|------------|-----|----------|------|
| A   | 25.40      | .25 | 1.000    | .010 |
| B   | 45°        | 5°  | 45°      | 5°   |
| C   | 5.71       | .13 | .225     | .005 |
| D   | 6.99 DIA   | .13 | .275 DIA | .005 |
| E   | 4.44       | .13 | .175     | .005 |
| F   | 1.52       | .13 | .060     | .005 |
| G   | 3.05       | .13 | .120     | .005 |
| H   | 12.95      | .25 | .510     | .010 |
| I   | 3.30       | .13 | .130     | .005 |
| J   | 16.64      | REF | .655     | REF  |
| K   | 0.13       | .02 | .005     | .001 |

**POWER OUTPUT VS POWER INPUT (TYPICAL)**



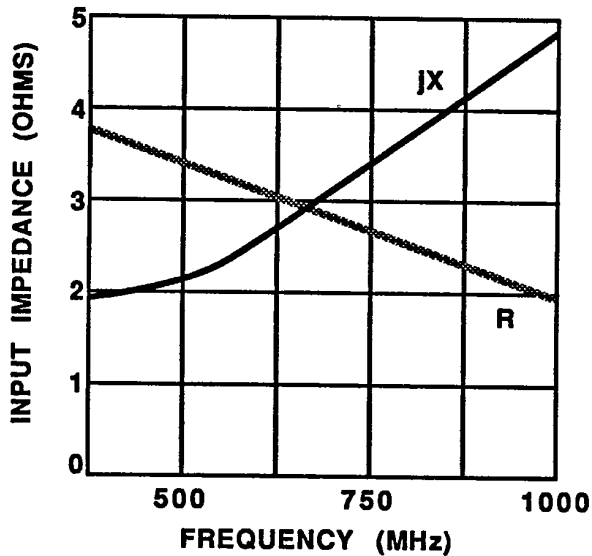
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**ELECTRICAL CHARACTERISTICS<sup>1</sup>**

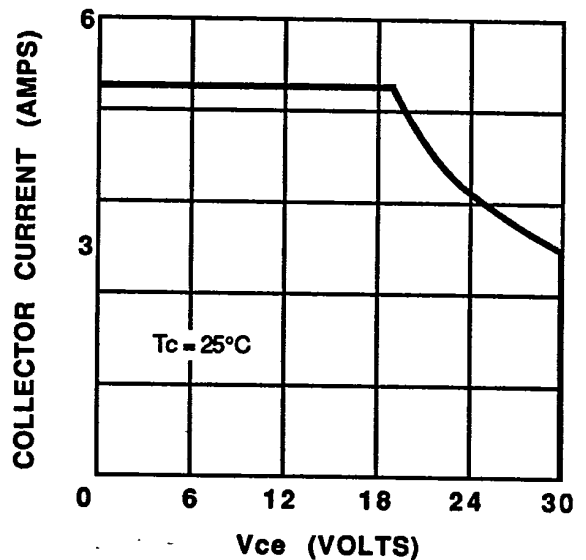
| SYMBOL            | CHARACTERISTICS                          | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |
|-------------------|--|---|------|------|------|-------|
| P <sub>out</sub>  | Power Output                             | f = 960 MHz<br>V <sub>cc</sub> = 28V<br>Class C | 4.0  |      |      | Watts |
| P <sub>in</sub>   | Power Input                              |   |      |      | 1.0  | Watts |
| P <sub>g</sub>    | Power Gain                               |   |      | 6.0  |      | dB    |
| η <sub>c</sub>    | Collector Efficiency                     |   |      |      | 60   | %     |
| BV <sub>ebo</sub> | Breakdown Voltage (Emitter to Base)      | I <sub>c</sub> = 0A, I <sub>e</sub> = 5mA       | 4.0  |      |      | Volts |
| BV <sub>ces</sub> | Breakdown Voltage (Collector to Emitter) | V <sub>be</sub> = 0A, I <sub>c</sub> = 20mA     | 50   |      |      | Volts |
| BV <sub>ceo</sub> | Breakdown Voltage (Collector to Emitter) | I <sub>b</sub> = 0A, I <sub>c</sub> = 50mA      | 30   |      |      | Volts |
| C <sub>ob</sub>   | Capacitance-Collector to Base            | V <sub>cb</sub> = 28V, f = 1MHz                 |      | 4.0  |      | pF    |
| h <sub>FE</sub>   | DC-Current Gain                          |   | 10   |      |      |       |
| θ <sub>jc</sub>   | Thermal Resistance                       | IR Scan; P <sub>d</sub> = 5W                    |      | 11   | 13   | °C/W  |
| L <sub>c</sub>    | Collector Inductance                     |   |      | 1.2  |      | nH    |

Note 1: T<sub>c</sub> = +25°C unless otherwise specified

**SERIES INPUT IMPEDANCE VS FREQUENCY (TYPICAL)**



**DC SAFE OPERATING AREA (TYPICAL)**



SPECIFICATIONS MAY BE SUBJECT TO CHANGE WITHOUT NOTICE

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